

Preliminary Technical Data

FEATURES

RF Frequency 500MHz to 1700MHz IF Range 40 – 350MHz Power Conversion Gain of 8.5dB SSB Noise Figure of 9.1dB SSB Noise Figure with 10dBm Blocker of 17dB Input IP3 of 26.5dBm Input P1dB of 10.6 dBm Typical LO Drive of 0 dBm Single-ended, 50Ω RF and LO Input Ports High Isolation SPDT LO Input Switch Single Supply Operation: 3.3 to 5 V Exposed Paddle 5 x 5 mm, 20 Lead LFCSP Package 2000V HBM / 500V FICDM ESD Performance

APPLICATIONS

Cellular Base Station Receivers Transmit Observation Receivers Radio Link Downconverters

GENERAL DESCRIPTION

The ADL5357 utilizes a highly linear doubly balanced passive mixer core along with integrated RF and LO balancing circuitry to allow for single-ended operation. The ADL5357 incorporates an RF balun allowing for optimal performance over a 500 to 1700 MHz RF input frequency range using high-side LO injection for RF frequencies between 500MHz to 1100MHz, and low side injection for RF frequencies between 1100MHz and 1700MHz. (For low side injection at RF Frequencies between 700MHz and 1100 MHz, please contact the factory.) The balanced passive mixer arrangement provides good LO to RF leakage, typically better than -25dBm, and excellent intermodulation performance. The balanced mixer core also provides extremely high input linearity allowing the device to be used in demanding cellular applications where in-band blocking signals may otherwise result in the degradation of dynamic performance. A high linearity IF buffer amp follows the passive mixer core, to yield a typical power conversion gain of 8.5dB, and can be utilized with a wide range of output impedances. (For a higher IIP3 version of the single mixer without the IF amplifiers, please contact the factory).

REV. PrD

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500-1700MHz Balanced Mixer with LO Buffer, IF Amp, and RF Balun ADL5357

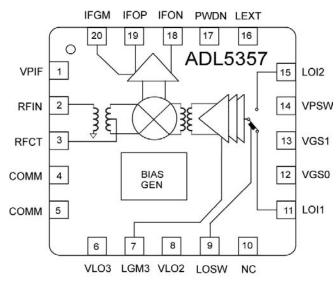


Figure 1. Functional Block Diagram

The ADL5357 provides two switched LO paths that can be utilized in TDD applications where it is desirable to ping-pong between two local oscillators. LO current can be externally set using a resistor to minimize DC current commensurate with the desired level of performance. An additional logic pin is provided to power down (<100uA) the circuit when desired.

For low voltage applications, the ADL5357 is capable if operation at voltages down to 3.3V with substantially reduced current.

The ADL5357 is fabricated using a BiCMOS high performance IC process. The device will be available in a 5mm x 5mm 20-lead LFCSP package and operates over a -40° C to $+85^{\circ}$ C temperature range. An evaluation board is also available.

RF Frequency	Single Mixer	Single Mixer + IF Amp	Dual Mixer + IF Amp
500MHz to 1700MHz	ADL5367	ADL5357	ADL5358
1200MHz to 2500MHz	ADL5365	ADL5355	ADL5356

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ADL5357—Specifications

 $Table \ 1. \ V_S = 5 \ V, \ T_A = 25^{\circ}C, \ f_{RF} = 900 \ MHz, \ f_{LO} = 1103 \ MHz, \ LO \ power = 0 \ dBm, \ Zo = 50\Omega, \ unless \ otherwise \ noted$

Parameter	Conditions	Min	Тур	Max	Unit
RF INPUT INTERFACE					
Return Loss	Tunable to >20dB over a limited bandwidth		13		dB
Input Impedance			50		Ω
RF Frequency Range		500		1700	MHz
OUTPUT INTERFACE					
Output Impedance	Differential impedance, $f = 200 \text{ MHz}$		200		Ω
IF Frequency Range		40		450	MHz
DC Bias Voltage ¹	Externally generated		Vs		v
LO INTERFACE					
LO Power		-3	0	+10	dBm
Return Loss			12		dB
Input Impedance			50		Ω
LO Frequency Range	High or Low Side LO Injection	700		1500	MHz
DYNAMIC PERFORMANCE					
Power Conversion Gain	Including 4:1 IF port transformer and PCB loss		8.5		dB
Voltage Conversion Gain	$Z_{\text{SOURCE}} = 50\Omega$, Differential $Z_{\text{LOAD}} = 200\Omega$ Differential		14.8		dB
SSB Noise Figure			9.1		dB
SSB Noise Figure Under-Blocking	10dBm Blocker present +/-5MHz from wanted RF input, LO source filtered		18		dB
Input Third Order Intercept	$f_{\text{RF1}}=900$ MHz, $f_{\text{RF2}}=901$ MHz, $f_{\text{LO}}=1103$ MHz, each RF tone at -10 dBm		26.5		dBm
Input Second Order Intercept	f_{RF1} = 900 MHz, f_{RF2} = 950 MHz, f_{LO} = 1103 MHz, each RF tone at -10 dBm		57		dBm
Input 1 dB Compression Point			10.6		dBm
LO to IF Output Leakage	Unfiltered IF Output		-11		dBm
LO to RF Input Leakage			-45		dBm
RF to IF Output Isolation			41		dB
IF/2 Spurious	-10 dBm Input Power		-70		dBc
IF/3 Spurious	-10dBm Input Power		-82		dBc
POWER INTERFACE					
Supply Voltage		3.3	5	5.5	v
Quiescent Current	Resistor Programmable		190		mA

¹ Supply voltage must be applied from external circuit through choke inductors

ADL5357—Specifications at VS=3.3V

Table 2. $V_s = 3.3 \text{ V}$, $T_A = 25^{\circ}\text{C}$, $f_{RF} = 900 \text{ MHz}$, $f_{LO} = 1103 \text{ MHz}$, LO power = 0 dBm, Zo = 50 Ω , unless otherwise noted

Parameter	Conditions	Min	Тур	Max	Unit
DYNAMIC PERFORMANCE					
Power Conversion Gain	Including 4:1 IF port transformer and PCB loss		9.5		dB
Voltage Conversion Gain	$Z_{\text{SOURCE}} = 50\Omega$, Differential $Z_{\text{LOAD}} = 200\Omega$ 16 Differential		dB		
SSB Noise Figure	Including 4:1 IF port transformer and PCB loss		8.6		dB
Input Third Order Intercept	f_{RF1} = 899.5 MHz, f_{RF2} = 900.5 MHz, f_{LO} = 1097 MHz, each RF tone at -10 dBm		19		dBm
Input Second Order Intercept	f_{RF1} = 900 MHz, f_{RF2} = 850 MHz, f_{LO} = 1097 MHz, each RF tone at -10 dBm	50		dBm	
Input 1 dB Compression Point			6		dBm
POWER INTERFACE					
Supply Voltage		3.0	3.3	3.6	v
Quiescent Current	Resistor Programmable		120		mA

ABSOLUTE MAXIMUM RATINGS

Table 2.

Parameter	Rating
Supply Voltage, V _{POS}	5.5 V
PWDN, LOSW, VGS0, VGS1	TBD
RF Input Power RFIN	TBD
Internal Power Dissipation	TBD
θ_{JA} (Exposed Paddle Soldered Down)	TBD
θ _{JC} (At Exposed Paddle)	TBD
Maximum Junction Temperature	TBD
Operating Temperature Range	-40°C to +85°C
Storage Temperature Range	–65°C to +150°C

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

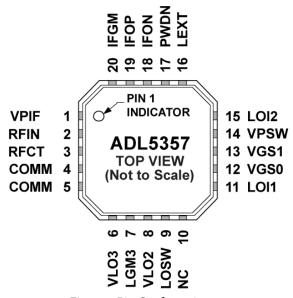


Figure 2. Pin Configuration

Table 3. Pin Function De	escriptions
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Pin No.	Mnemonic	Function
1	VPIF	Positive Supply Voltage for IF Amplifier: 5.00 V.
2	RFIN	RF Input. Must be ac-coupled.
3	RFCT	RF Balun Center Tap (AC Ground).
4, 5	СОММ	Device Common (DC Ground).
6, 8	VLO3, VLO2	Positive Supply Voltage for LO Amplifier.
7	LGM3	LO Amplifier Bias Control.
9	LOSW	LO Switch.
10	NC	No Connect.
11, 15	LOI1, LOI2	LO Input. Must be ac-coupled.
12, 13	VGS0, VGS1	Mixer Gate Bias Control. Ground for nominal operation.
14	VPSW	Positive Supply Voltage for LO Switch.
16	LEXT	IF Return (Ground)
17	PWDN	Connect to Ground for Normal Operation. Connect pin to 3.3V for disable mode.
18, 19	IFON, IFOP	Differential IF output (Open Collectors). Each requires DC bias of 5.00 V (Nominal).
20	IFGM	IF Amplifier Bias Control.

ADL5357

TYPICAL PERFORMANCE CHARACTERISTICS

 $V_S = 5 V$, $T_A = 25^{\circ}C$, as measured using typical circuit schematic with high-side LO unless otherwise noted.

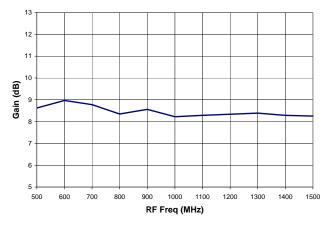


Figure 3. Conversion Gain versus RF Frequency

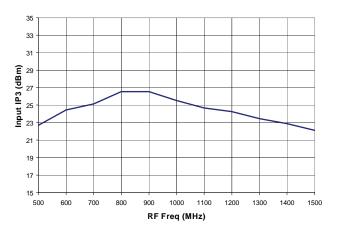


Figure 4. IIP3 versus RF Frequency

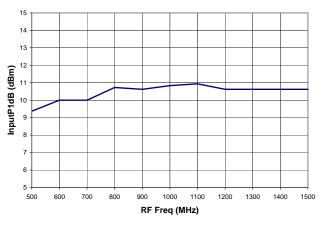


Figure 5. IP1dB versus RF Frequency

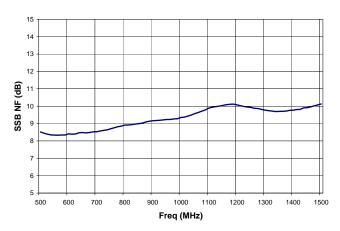


Figure 6. Single-Sideband NF versus RF Frequency

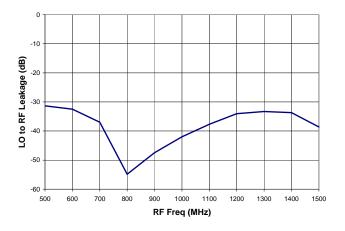


Figure 7. LO to RF Leakage versus LO Frequency

EVALUATION BOARD

An evaluation board is available for the family of double balanced mixers, including ADL5355 and ADL5357. The standard evaluation board schematic is presented in Figure 8. The evaluation board is fabricated on a multilayer Rogers board. Table 4 details the various configuration options of the evaluation board.

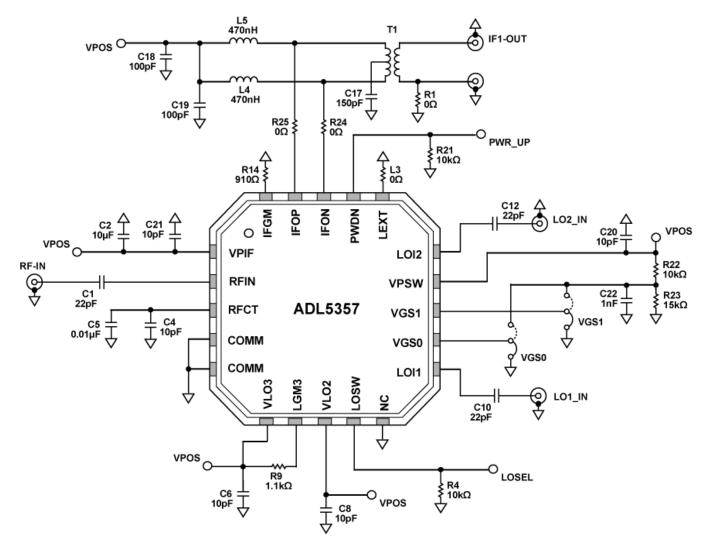


Figure 8. Evaluation Board Schematic.

Components	Function	Default Conditions	
C2, C6, C8, C18, C19, C20, C21	Power Supply Decoupling. Nominal supply decoupling consists a 10 µF capacitor to ground in parallel with 10pF capacitors to ground	$C_2 = 10 \mu\text{F}$ (size 0603)	
C21	positioned as close to the device as possible.	C6, C8, C20, C21 = 10 pF (size 0402) C18, C19 = 100 pF (size 0402)	
C1, C4, C5	RF Input Interface. The input channels is ac-coupled through C1. C4 and C5 provide bypassing for the center taps of the RF input baluns.	C1 = 22 pF (size 0402)	
		C4 = 10 pF (size 0402)	
		C5 = 0.01 µF (size 0402)	
T1, C17, L4, L5, R1, R24,	IF Output Interface. The open collector IF output interfaces are	C17 = 150 pF (size 0402)	
R25	biased through pull-up choke inductors L4 and L5. T1is a 4:1 impedance transformer used to provide a single ended IF output interface, with C17 providing center-tap bypassing. R1 should be	T1 = TC4-1W+ (MiniCircuits)	
		L4, L5 = 470 nH (size 1008)	

	removed for balanced output operation.	R1, R24, R25 = 0Ω (size 0402)
C10, C12, R4	LO Interface. C10 and C12 provide ac-coupling for the LO1_IN and	C10, C12 = 10pF (size 0402)
	LO2_IN local oscillator inputs. LOSEL selects the appropriate LO input for both mixer cores. R4 provides a pull-down to ensure LO1_IN is enabled when the LOSEL test point has logic low. LO2_IN is enabled when LOSEL is pulled to logic high.	R4 = 10kΩ (size 0402)
R21	PWDN Interface. R21 pulls the PWDN logic low and enables the device. PWR_UP test point allows PWDN interface to be excercised using external logic generator. It is permissible to ground the PWDN pin for nominal operation.	R21 = 10kΩ (size 0402)
C22, L3, R9, R14, R22, R23, VGS0, VGS1	Bias Control. R22 and R23 form a voltage divider to provide a 3V for logic control, bypassed to ground through C22. VGS0 and VGS1 jumpers provide programmability at pin VGS0 and VGS1. It is recommeded to pull these two pins to ground for nominal operation. R9 sets the bias point for the internal LO buffers. R14 sets the bias point for the internal IF amplifiers.	C22 = 1 nF (size 0402)
		$L3 = 0 \Omega$ (size 0603)
		$R9 = 1.1 \text{ k}\Omega$ (size 0402)
		R14 = 910 Ω (size 0402)
		R22 = $10k\Omega$ (size 0402)
		$R23 = 15k\Omega$ (size 0402)
		VGS0 = VGS1 = 3-pin shunt

OUTLINE DIMENSIONS

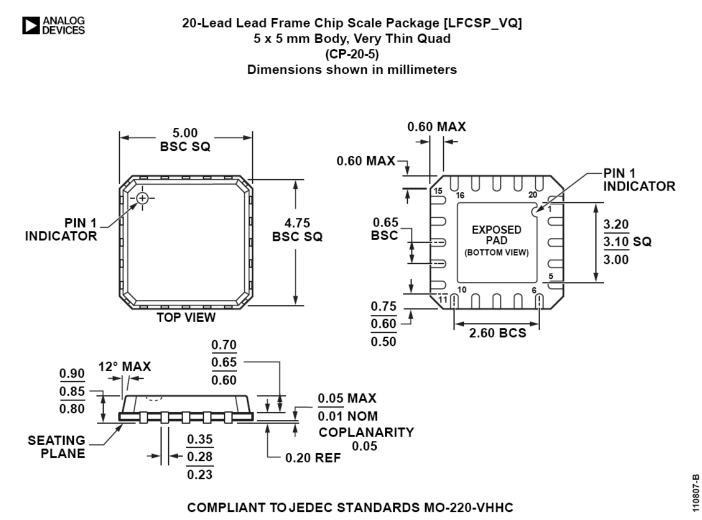


Figure 9. 20-Lead Lead Frame Chip Scale Package [LFCSP_VQ] 5 mm × 5 mm Body, Very Thin Quad (CP-20-5)) Dimensions shown in millimeters

ORDERING GUIDE

Models	Temperature Range	Package Description	Package Option	Branding	Transport Media Quantity
ADL5357XCPZ-R71	-40°C to +85°C	20-Lead Lead Frame Chip Scale Package [LFCSP_VQ]	CP-20-5	TBD	TBD, Reel
ADL5357-EVALZ		Evaluation Board			1

 $^{1}Z = Pb$ -free part.